國立成功大學九十五學年度碩士班招生考試試題

編號: 7,204 系所: 奈米科技暨微系統工程研究所

科目:電子電路學

本試題是否可以使用計算機: ☑可使用 , □不可使用 (請命題老師勾選)

1. If a voltage source $V(t) = 100\sin 10t$ Volt is applied onto a RL series circuit with $R = 100\Omega$, L = 20H and the initial current=0, please find the current in the circuit i(t) = ?(10%)

- 2. For a p-n junction with $N_a=10^{17}/\text{cm}^3$ and $N_d=10^{16}/\text{cm}^3$, find, at T=300k, the built-in voltage (5%) and the width of the depletion region (15%). Use $n_i=1.5\times10^{10}/\text{cm}^3$.
- 3. The 6.8V zener diode in the circuit of figure 1 is specified to have $V_Z = 6.8V$ at $I_Z = 5 \text{mA}$, $r_Z = 20 \Omega$, and $I_{ZK} = 0.2 \text{mA}$. The supply voltage V^+ is 10V. Find V_0 when $R_L = 2k \Omega$ (15%)
- 4. For the transfer function, $A_{\nu}(s) = \frac{8 \times 10^{13} \, s(s+20)}{(s+30)(s+400)(s+10000)(s+100000)}$, (a) please write down the poles and zeros. (5%) (b) please state which pole is the dominant low frequency pole and which frequency is the dominant high frequency pole (5%) please sketch the Bode magnitude plot (5%)
- 5. Assuming the op amp in figure 2 is ideal, derive an expression for the closed loop gain v_0/v_1 of the circuit (15%)
 - 6. For the circuit shown in figure 3, if we already know the values of β , r_0 , r_{π} , r_e and g_m find $A_M=? \omega_L=? (25\%)$

